AVALANCHE FAST SOFT-RECOVERY RECTIFIER DIODES

Glass passivated rectifier diodes in hermetically sealed axial-leaded glass envelopes. They are intended for television and industrial applications, such as switched-mode power supplies, scan rectifiers, in TV receivers, and also for use in inverter and converter applications. The devices feature non-snap-off (soft-recovery) switching characteristics and are capable of absorbing reverse transient energy (e.g. during flashover in the picture tube).

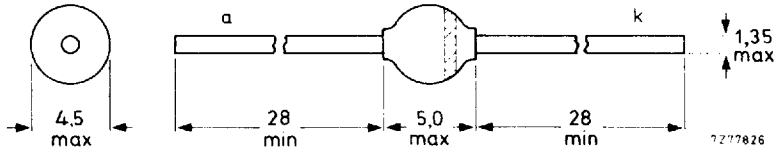
QUICK REFERENCE DATA

			BYW95A	B	C	
Repetitive peak reverse voltage	V_{RRM}	max.	200	400	600	V
Continuous reverse voltage	V_R	max.	200	400	600	V
Average forward current	$I_{F(AV)}$	max.		3		A
Non-repetitive peak forward current	I_{FSM}	max.		70		A
Non-repetitive peak reverse energy	E_{RSM}	max.		10		mJ
Reverse recovery time	t_{rr}	<		250		ns

MECHANICAL DATA

Dimensions in mm

Fig. 1 SOD-64.



The marking band indicates the cathode.

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

			BYW95A	B	C	
Repetitive peak reverse voltage	V_{RRM}	max.	200	400	600	V
Continuous reverse voltage	V_R	max.	200	400	600	V
Average forward current (averaged over any 20 ms period)						
T_{tp} = 60 °C; lead length 10 mm	$I_{F(AV)}$	max.		3		A
T_{amb} = 65 °C; Fig. 2	$I_{F(AV)}$	max.		1,25		A
Repetitive peak forward current	I_{FRM}	max.		15		A
Non-repetitive peak forward current (t = 10 ms; half sine-wave) $T_j = T_{j\,max}$ prior to surge; $V_R = V_{RRMmax}$	I_{FSM}	max.		70		A
Non-repetitive peak reverse avalanche energy; I_R = 400 mA; $T_j = T_{j\,max}$ prior to surge; with inductive load switched off	E_{RSM}	max.		10		mJ
Storage temperature	T_{stg}			−65 to + 175		°C
Operating junction temperature	T_j	max.		175		°C

THERMAL RESISTANCE

Influence of mounting method

1. Thermal resistance from junction to tie-point at a lead length of 10 mm	$R_{th\ j\text{-}tp}$	=	25	K/W
2. Thermal resistance from junction to ambient when mounted on a 1,5 mm thick epoxy-glass printed-circuit board; Cu-thickness ⩾ 40 μm; Fig. 2 (see "Thermal model")	$R_{th\ j\text{-}a}$	=	75	K/W

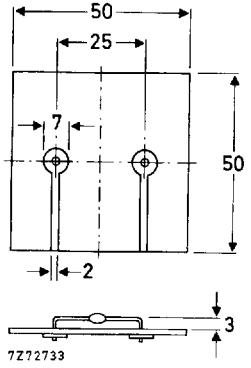


Fig. 2 Mounted on a printed-circuit board.

CHARACTERISTICS

T_j = 25 °C unless otherwise specified

			BYW95A	B	C	
Forward voltage						
I_F = 5 A	V_F	<	1,5	1,5	1,5	V *
I_F = 5 A; $T_j = T_{j\,max}$	V_F	<	1,25	1,25	1,25	V *
Reverse avalanche breakdown voltage						
I_R = 0,1 mA	$V_{(BR)R}$	>	300	500	700	V
Reverse current						
$V_R = V_{RRMmax}$; T_j = 165°	I_R	<		150		μA
Reverse recovery when switched from I_F = 1 A to $V_R \geqslant$ 30 V with $-dI_F/dt$ = 20 A/μs						
recovered charge	Q_s	<		250		nC
recovery time	t_{rr}	<		250		ns
Maximum slope of reverse recovery current when switched from I_F = 1 A to $V_R \geqslant$ 30 V with $-dI_F/dt$ = 1 A/μs	$\lvert dI_R/dt \rvert$	<		6		A/μs

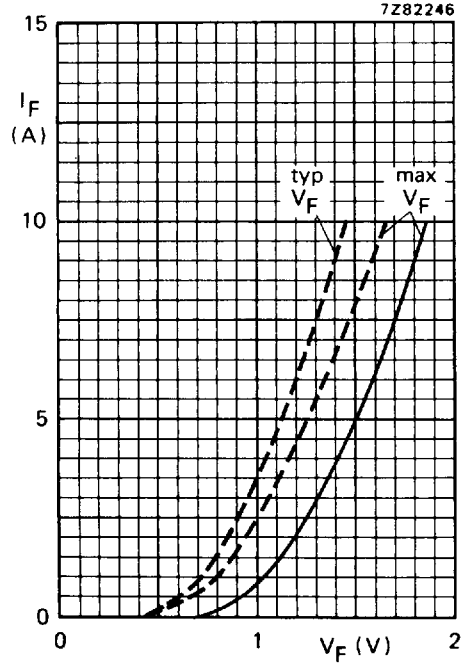


Fig. 3 —— T_j = 25 °C; – – – $T_j = T_{j\,max}$.

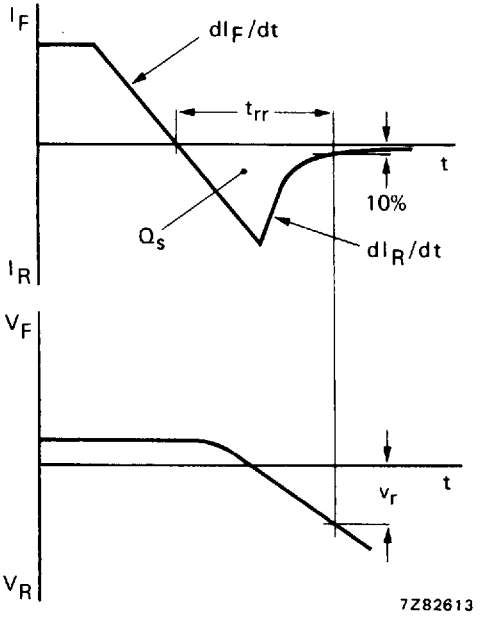


Fig. 4 Definitions.

* Measured under pulse conditions to avoid excessive dissipation.

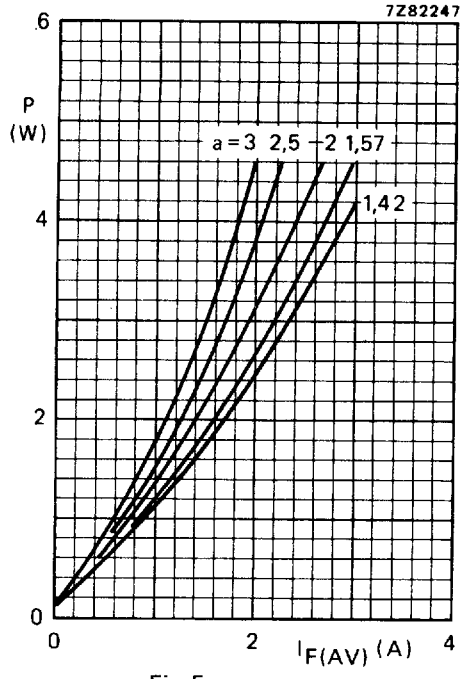


Fig. 5.

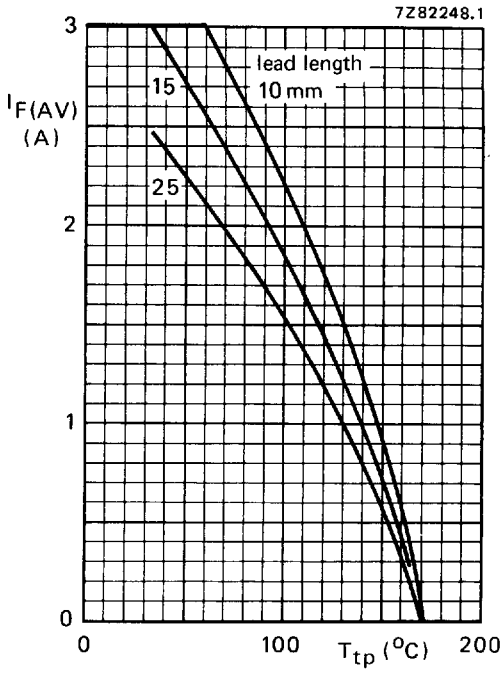


Fig. 6.

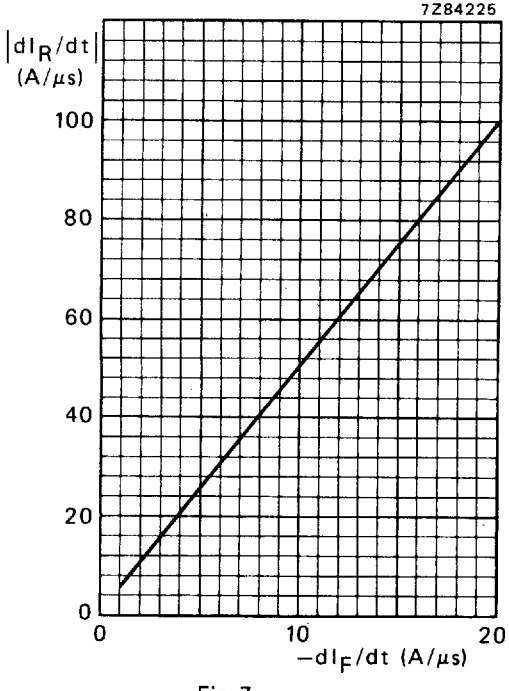


Fig. 7.

Fig. 5 Steady state power dissipation (forward plus leakage current) excluding switching losses as a function of the average forward current.

The graph is for switched-mode application.

$a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$

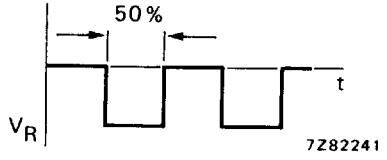


Fig. 6 Maximum average forward current as a function of the tie-point temperature; the curves include losses due to reverse leakage.

The graph is for switched-mode application; $V_R = V_{RRMmax}$; $\delta = 50\%$; a = 1,57.

Fig. 7 Maximum slope of reverse recovery current. $T_j = 25$ °C.

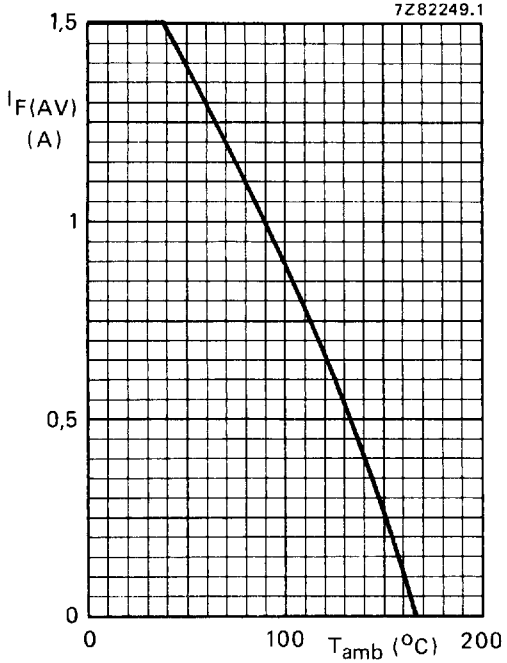


Fig. 8 Maximum average forward current as a function of the ambient temperature; the curve includes losses due to reverse leakage.
Mounting method see Fig. 2.

The graph is for switched-mode application; $V_R = V_{RRMmax}$; $\delta = 50\%$; a = 1,57.

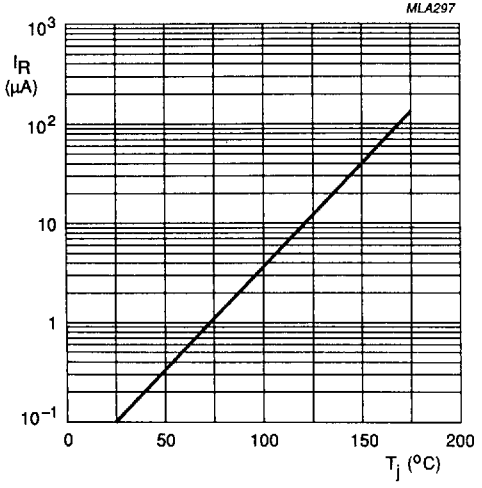


Fig. 9 Reverse current as a function of junction temperature. $V_R = V_{RRM\,max}$. Typical values.

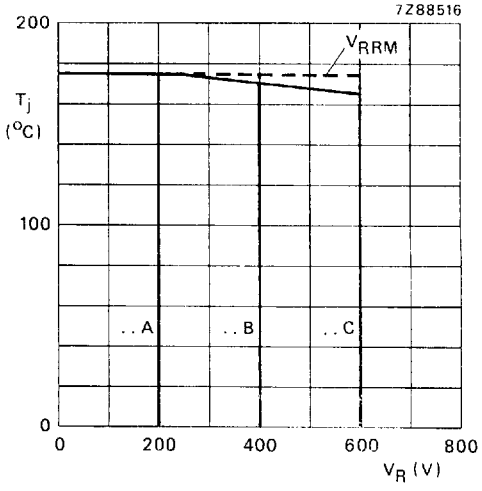


Fig. 10 Maximum values junction temperature as a function of reverse voltage.

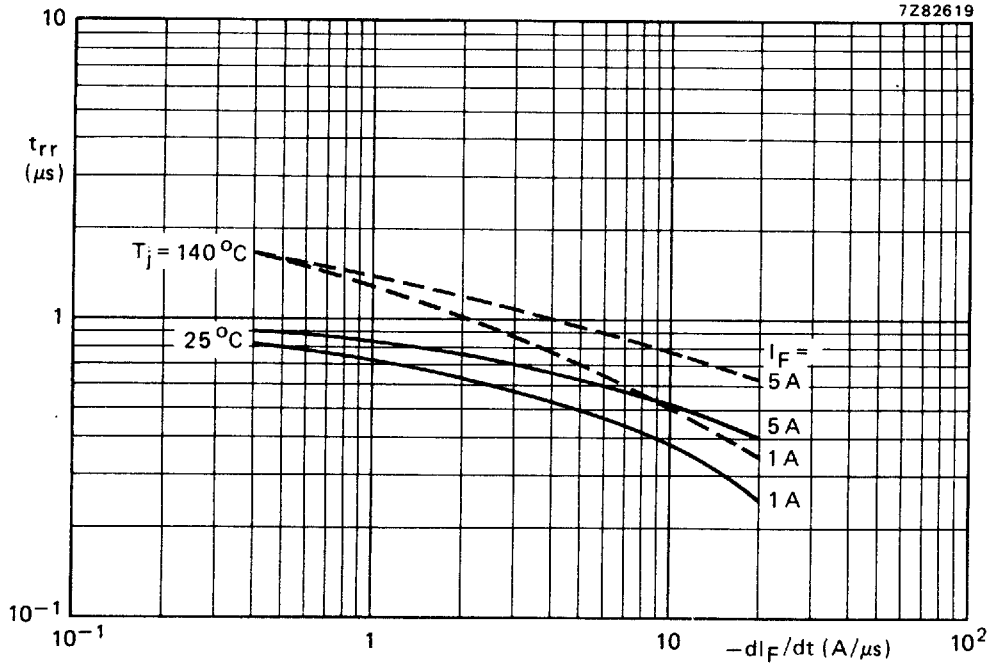


Fig. 11 Maximum values; for definitions see Fig. 4.

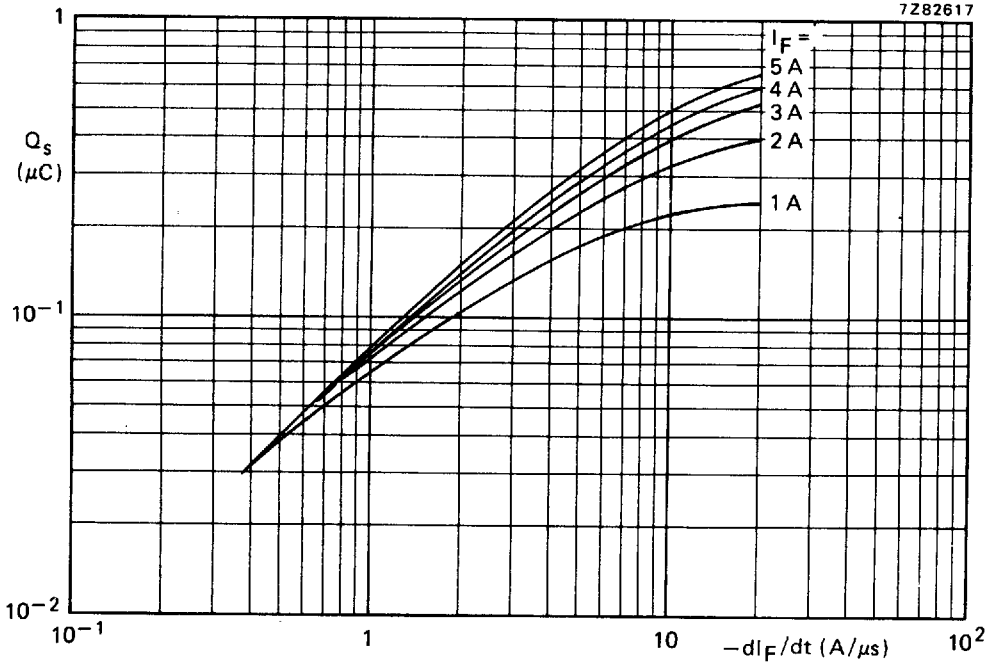


Fig. 12 Maximum values; T_j = 25 °C. For definitions see Fig. 4.

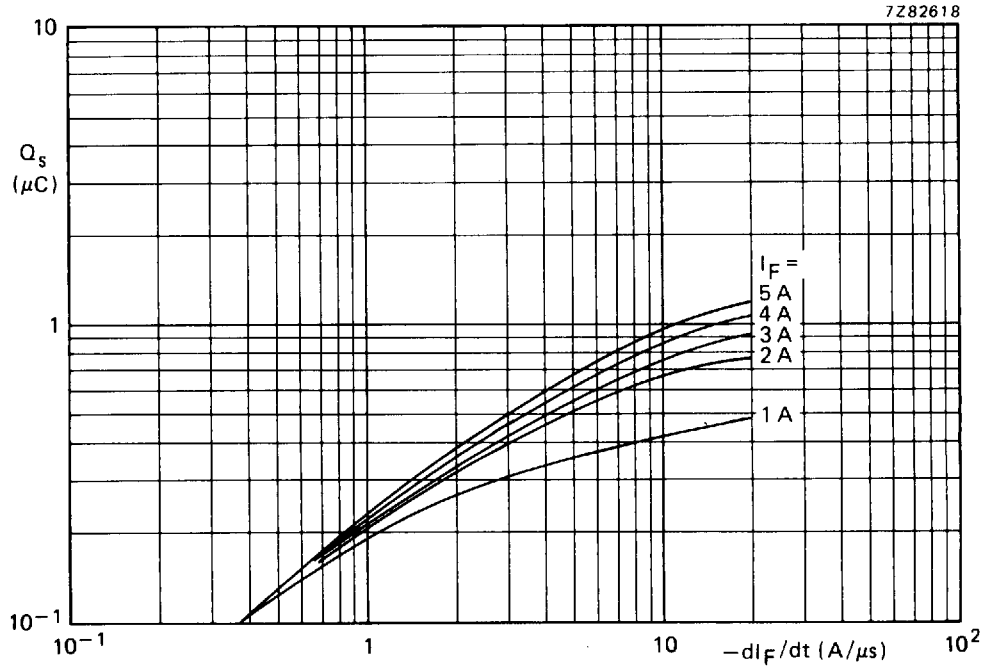


Fig. 13 Maximum values; T_j = 140 °C. For definitions see Fig. 4.